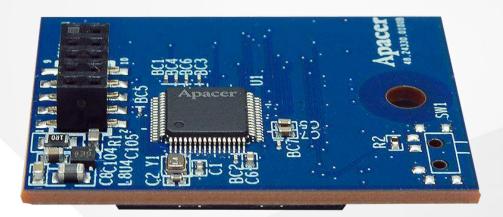


RoHS Recast Compliant

USB-Disk Module 2A

Low-Profile 90D Product Specifications



December 24, 2020

Version 1.9



Apacer Technology Inc.

1F, No.32, Zhongcheng Rd., Tucheng Dist., New Taipei City, Taiwan, R.O.C Tel: +886-2-2267-8000 Fax: +886-2-2267-2261 www.apacer.com

Specifications Overview:

- USB2.0 High-Speed and USB1.1 Full-Speed Compatible Interface
- Capacity
 - 256, 512 MB
 - 1, 2, 4, 8, 16, 32 GB
- Performance*
 - Sequential read: Up to 44 MB/sec
 - Sequential write: Up to 41 MB/sec
 - Random read (4K): Up to 2,400 IOPS
 - Random write (4K): Up to 105 IOPS
- Flash Management
 - Flash bad-block management
 - Global Wear Leveling
 - BCH (72 bit) Error Detection Code/Error Correction Code (EDC/ECC)
 - S.M.A.R.T.
 - Power Failure Management
- Supports Non-Removable Setting
- NAND Flash Type: SLC
- MTBF: >2,000,000 hours
- Endurance (in Terabytes Written: TBW)
 - 256 MB: 13 TBW
 - 512 MB: 26 TBW
 - 1 GB: 54 TBW
 - 2 GB: 108 TBW
 - 4 GB: 219 TBW
 - 8 GB: 438 TBW
 - 16 GB: 884 TBW
 - 32 GB: 1,752 TBW

Temperature Range

Operating:

Standard: 0°C to 70°C

Wide: -40°C to 85°C

Storage: -40°C to 100°C

Supports Boot-up Function for OS

- Windows: WinXP/7 or later

Mac: 10.2.8 or later

Linux: 2.4.10 or later

Power Consumption*

- Operating voltage: 5V (with a certain percentage of tolerance)
- Active mode: 110 mA
- Idle mode: 45 mA

Connector

- 10-pin (2x5) female header in 2.00mm
- Write Protect Switch (optional)
- RoHS Recast Compliant

^{*}Varies from capacities. The values for performances and power consumptions presented are typical and may vary depending on flash configurations or platform settings.

Table of Contents

1. General Descriptions	3
1.1 Performance-optimized Controller	3
1.1.1 Error Correction Code (ECC)	3
1.1.2 Global Wear Leveling	3
1.1.3 Write Protection Mode (optional)	3
1.1.4 Power Failure Management	3
2. Functional Block	4
3. Pin Assignments	5
4. Product & Reliability Specifications	6
4.1 Capacity Specifications	6
4.2 Performance Specifications	6
4.3 Environmental Specifications	7
4.4 Mean Time Between Failures (MTBF)	7
4.5 Certification and Compliance	7
4.6 Endurance	8
5. Electrical Specifications	9
5.1 Operating Conditions	9
5.2 Absolute Maximum Rating	9
5.3 Power Consumption	9
5.4 AC Characteristics	
6. Physical Dimensions	11
6.1 Low Profile Design (LP 90D)	11
6.2 Write Protect Switch (optional)	12
7. Product Ordering Information	13
7.1 Product Code Designations	13
7.2 Valid Combinations	14
7.2.1 Low Profile 90 Degree Mounting Screw	14
7 2 2 NR Low Profile 90 Degree Mounting Screw	14

1. General Descriptions

Apacer's USB-Disk Module (UDM) 2A LP 90D is a high performance, embedded solid state drive (SSD) designed to replace a conventional IDE hard disk drive. UDM SSD can be plugged into a standard Embedded USB connector commonly found in desktops, portable PC systems and industrial PC systems. This product is well suited for embedded flash storage applications offering new and expanded functionality as well as more cost-effective designs, better performance and increased reliability.

1.1 Performance-optimized Controller

The heart of an UDM is the USB controller, which translates standard USB signals into the data and controls of the flash media. This proprietary USB controller is specifically designed to attain high data throughput from host to flash.

1.1.1 Error Correction Code (ECC)

The UDM uses BCH Error Detection Code (EDC) and Error Correction Code (ECC) algorithms which correct up to 72bit random single-bit errors for each 1024-byte block of data depending on spare area of flash memory. High performance is achieved through hardware-based error detection and correction.

1.1.2 Global Wear Leveling

Flash memory can be erased a limited number of times, This number is called the erase cycle limit, or write endurance limit, The erase cycle limit applies to each individual erase block in the flash device.

In a typical application, and especially if a file system is used, specific pages are constantly updated (e.g., the page that contains the FAT, registry, etc.). Without any special handling, these pages would wear out more rapidly than other pages, reducing the lifetime of the entire flash.

To overcome this inherent deficiency, Apacer's USB-Disk Module (UDM) uses Global Wear Leveling algorithm. This algorithm ensures that consecutive writes of a specific sector are not written physically to the same page in the flash. This spreads flash media usage evenly across all pages, thereby maximizing flash lifetime.

The Global Wear Leveling mechanism provides write/erase cycles for reliable data storage over an extended period.

1.1.3 Write Protection Mode (optional)

When the device is configured to the Write-Protection mode, it enhances the data security and protection. This feature prevents the stored data from inadvertent system writes or erases, and viruses.

1.1.4 Power Failure Management

Power Failure Management plays a crucial role when power supply becomes unstable. Power disruption may occur when users are storing data into the SSD, leading to instability in the drive. However, with Power Failure Management, a firmware protection mechanism will be activated to scan pages and blocks once power is resumed. Valid data will be transferred to new blocks for merging and the mapping table will be rebuilt. Therefore, data reliability can be reinforced, preventing damage to data stored in the NAND Flash.

2. Functional Block

The USB-Disk Module (UDM) contains a controller, embedded firmware, and Flash Media with a female connector. The UDM interfaces with the host system allowing data to be written to and read from the Flash Media.

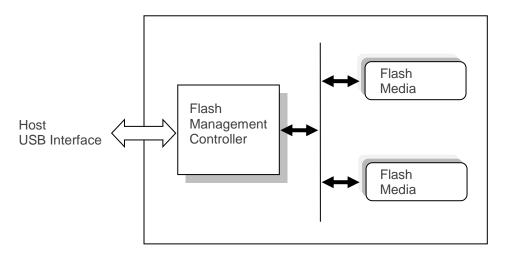


Figure 2-1 Functional Block Diagram

3. Pin Assignments

This chapter provides information on the pin assignments and signal descriptions.

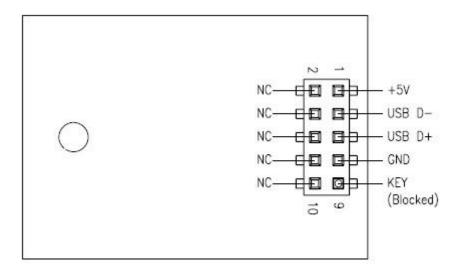


Table 3-1 Pin Assignment of the 10-pin Configuration

Pin	Signal	Pin	Signal
1	+5V	2	N.C
3	USB D-	4	N.C
5	USB D+	6	N.C
7	GND	8	N.C
9	Key (Blocked)	10	N.C

4. Product & Reliability Specifications

4.1 Capacity Specifications

The USB-Disk Module product family is available as shown in Table 4-1.

Table 4-1 Capacity Specifications

Capacity	Total Bytes
256 MB	250,314,752
512 MB	500,924,416
1 GB	998,998,016
2 GB	2,001,502,208
4 GB	4,001,382,400
8 GB	8,002,748,416
16 GB	16,022,257,664
32 GB	32,010,944,512

Note: The number of total bytes may vary depending on the file system in use.

4.2 Performance Specifications

Performance of the USB-Disk Module product is listed below in Table 4-2.

Table 4-2 Performance Specifications

Capacity Performance	256 MB	512 MB	1 GB	2 GB	4 GB	8 GB	16 GB	32 GB
Sequential Read* (MB/s)	44	44	44	44	44	44	44	44
Sequential Write* (MB/s)	10	20	35	36	38	40	41	41
Random Read IOPS** (4K)	2,400	2,400	2,000	1,900	1,800	1,700	1,600	1,600
Random Write IOPS** (4K)	45	60	50	50	70	80	105	105

Note:

Results may differ from various flash configurations or host system setting.

^{*}Sequential performance is based on CrystalDiskMark 5.2.1 with file size 1,000MB.

^{**}Random performance measured using IOMeter with Queue Depth 32.

4.3 Environmental Specifications

Environmental specification of the USB-Disk Module product family is available as shown in Table 4-3.

Table 4-3 Environmental Specifications

Item	Specifications					
Temperature	Operation	0°C to 70°C (Standard); -40°C to 85°C (Wide)				
Temperature	Storage	-40°C to 100°C				
Shock	Operating	50(G)/11(ms)/half sine (compliant with MIL-STD-202G)				
SHOCK	Non-operating	1,500(G)/0.5(ms)/half sine (compliant with MIL-STD-202G)				
\/ib = to =	Operating	7.69(Grms), 20~2000(Hz)/random (compliant with MIL-STD-810G)				
Vibration	Non-operating	4.02(Grms), 15~2000(Hz)/random (compliant with MIL-STD-810G)				
EMC	FCC, CE					

4.4 Mean Time Between Failures (MTBF)

Mean Time Between Failures (MTBF) is predicted based on reliability data for the individual components in Apacer's USB flash drive. Serving as statistical reference, the prediction result for Apacer's USB is more than 2,000,000 hours.

Note: The MTBF is predicated and calculated based on "Telcordia Technologies Special Report, SR-332, Issue 2" method.

4.5 Certification and Compliance

The USB-Disk Module (UDM) complies with the following standards:

- CE
- FCC
- RoHS Recast
- MIL-STD-810

4.6 Endurance

The endurance of a storage device is predicted by TeraBytes Written based on several factors related to usage, such as the amount of data written into the drive, block management conditions, and daily workload for the drive. Thus, key factors, such as Write Amplifications and the number of P/E cycles, can influence the lifespan of the drive.

Table 4-4 Endurance Specifications

Capacity	TeraBytes Written
256 MB	13
512 MB	26
1 GB	54
2 GB	108
4 GB	219
8 GB	438
16 GB	884
32 GB	1,752

Note:

- The estimated values are based on sequential write behavior. (Apacer EDTestTool, test mode – sequential data pattern –100.00% of disk space with 128K) Flash vendor guaranteed SLCP/E cycle: 60K
- WAF may vary from capacity, flash configurations and writing behavior on each platform.
- 1 Terabyte = 1024GB

5. Electrical Specifications

5.1 Operating Conditions

Table 5-1 lists the absolute stress rating for the USB-Disk Module.

Caution: Absolute Maximum Stress Ratings - Applied conditions greater than those listed under "Absolute Maximum Stress Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these conditions or conditions greater than those defined in the operational sections of this data sheet is not implied. Exposure to absolute maximum stress rating conditions may affect device reliability.

Table 5-1 Operating Range

Range	Ambient Temperature	Voltage
Standard Temperature	0°C to 70°C	45.554
Wide Temperature	-40°C to 85°C	4.5-5.5V

5.2 Absolute Maximum Rating

Table 5-2 lists the absolute maximum power ratings for the USB-Disk Module.

Table 5-2 Absolute maximum power pin stress ratings

Parameter	Symbol	Min	Max	Unit
Power Supply Input	VDD- VSS	-0.3	5.5	V
Voltage on any pin except VDD with respect to GND	VIN	-ss - 0.3	VDD +0.3	V

5.3 Power Consumption

Table 5-3 lists the power consumption for the USB-Disk Module.

Table 5-3 Power Consumption

Capacity Mode	216 MB	512 MB	1 GB	2GB	4 GB	8 GB	16 GB	32 GB
Active (mA)	85	85	95	105	100	95	95	110
Standby (mA)	40	40	40	45	40	40	40	45

^{*}All values are typical and may vary depending on flash configurations or host system settings.

**Active power is an average power measurement performed using CrystalDiskMark with 128KB sequential read/write transfers.

5.4 AC Characteristics

Table 5-4 AC Characteristics Full Speed

Parameter	Symbol	Min	Тур	Max	Unit
Rise Time	T _{FR}	4	_	20	ns
Fall Time	T _{FF}	4	_	20	ns
Differential Rise and Fall Time Matching	T _{FRFM}	90		111.11	%
Driver Output Resistance	Z_{DRV}	28	_	44	Ω

Table 5-5 AC Characteristics High Speed

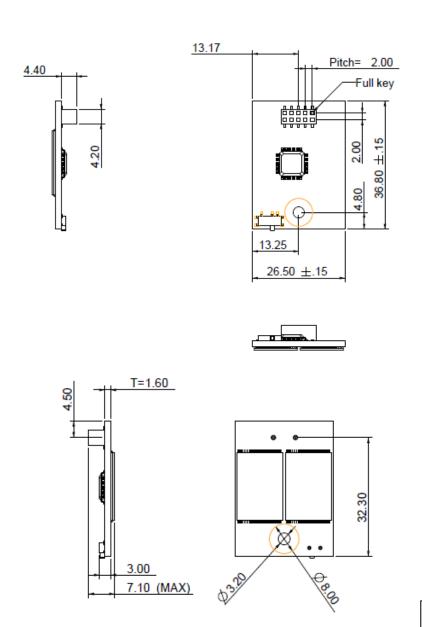
Parameter	Symbol	Min	Тур	Max	Unit
Rise Time (10%~90%)	T_{HSR}	500	_	_	ps
Fall Time (10%~90%)	T _{HSF}	500	_	_	ps
Driver Output Resistance	Z _{HSDRV}	40.5	_	49.5	Ω

6. Physical Dimensions

6.1 Low Profile Design (LP 90D)

Length	Width	Height (Max)
36.80mm	26.50mm	7.10mm



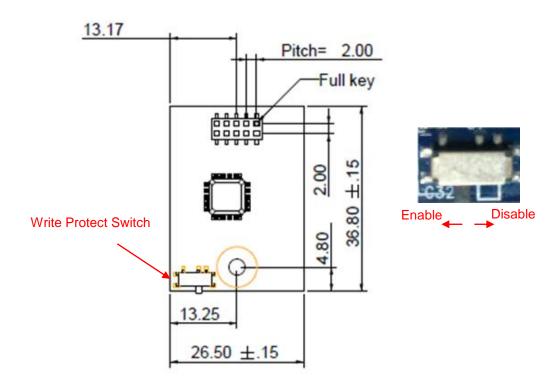


Unit: mm

Tolerance: ±0.2

6.2 Write Protect Switch (optional)

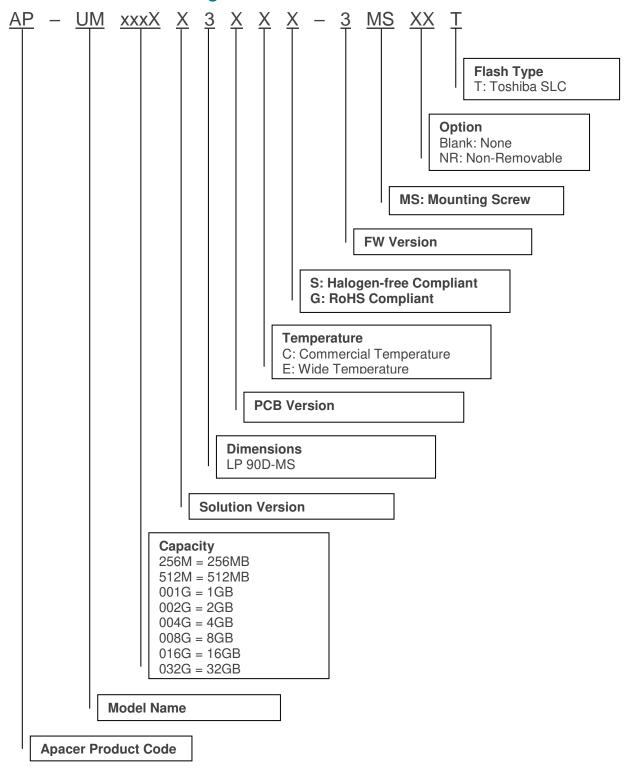
Apacer implements the Virtual Write scheme that allows write commands to go through the flash controller and data temporarily stored, but no data has been actually written into the flash. Once the system is reset and rebooted, the temporarily stored data will be lost and nowhere to be found in the system. Since the Virtual Write scheme runs at device level, it requires no software or driver installation and is independent from the host OS.



Unit: mm Tolerance: ±0.2

7. Product Ordering Information

7.1 Product Code Designations



7.2 Valid Combinations

7.2.1 Low Profile 90 Degree Mounting Screw

Capacity	Standard Temperature	Wide Temperature	
256MB	AP-UM256MA30CS-3MST	AP-UM256MA30ES-3MST	
512MB	AP-UM512MA30CS-3MST	AP-UM512MA30ES-3MST	
1GB	AP-UM001GA30CS-3MST	AP-UM001GA30ES-3MST	
2GB	AP-UM002GA30CS-3MST	AP-UM002GA30ES-3MST	
4GB	AP-UM004GA30CS-3MST	AP-UM004GA30ES-3MST	
8GB	AP-UM008GA30CS-3MST	AP-UM008GA30ES-3MST	
16GB	AP-UM016GA30CS-3MST	AP-UM016GA30ES-3MST	
32GB	AP-UM032GA30CS-3MST	AP-UM032GA30ES-3MST	

7.2.2 NR Low Profile 90 Degree Mounting Screw

Capacity	Standard Temperature	Wide Temperature	
256MB	AP-UM256MA30CS-3MSNRT	AP-UM256MA30ES-3MSNRT	
512MB	AP-UM512MA30CS-3MSNRT	AP-UM512MA30ES-3MSNRT	
1GB	AP-UM001GA30CS-3MSNRT	AP-UM001GA30ES-3MSNRT	
2GB	AP-UM002GA30CS-3MSNRT	AP-UM002GA30ES-3MSNRT	
4GB	AP-UM004GA30CS-3MSNRT	AP-UM004GA30ES-3MSNRT	
8GB	AP-UM008GA30CS-3MSNRT	AP-UM008GA30ES-3MSNRT	
16GB	AP-UM016GA30CS-3MSNRT	AP-UM016GA30ES-3MSNRT	
32GB	AP-UM032GA30CS-3MSNRT	AP-UM032GA30ES-3MSNRT	

Note: Valid combinations are those products in mass production or will be in mass production. Consult your Apacer sales representative to confirm availability of valid combinations and to determine availability of new combinations.

Revision History

Revision	Description	Date
1.0	Official release	1/3/2017
1.1	Added 128MB support	1/9/2019
1.2	 Removed 128MB support Updated the description of Connector on Features page Added 4.5 Certification and Compliance Modified the signal of pin 9 to blocked for Type A, B, and C Modified the flash type mentioned in 7.1 Product Code Designations to SLC 	4/6/2017
1.3	Added a product photo	4/7/2017
1.4	Updated the product photo	4/17/2017
1.5	- Changed Advanced Wear-Leveling to Global Wear Leveling - Updated MTBF to >2,000,000 hours - Added IOPS performance	11/15/2017
1.6	- Removed Extended Data Protection and added Write Protect Switch (optional) on Features page - Added 6.2 Write Protect Switch (optional)	11/15/2017
1.7	- Renamed extended temperature to wide temperature - Updated Table 4-3 by changing storage temperature from - 40°C to 85°C to -40°C to 100°C	8/14/2020
1.8	- Added Power Failure Management to Flash Management on Specifications Overview page - Added 1.1.4 Power Failure Management	11/6/2020
1.9	- Added Endurance section to Specifications Overview page - Added 4.6 Endurance	12/24/2020

Global Presence

Taiwan (Headquarters)

Apacer Technology Inc.

1F., No.32, Zhongcheng Rd., Tucheng Dist., New Taipei City 236, Taiwan R.O.C.

Tel: 886-2-2267-8000 Fax: 886-2-2267-2261 amtsales@apacer.com

Japan

Apacer Technology Corp.

6F, Daiyontamachi Bldg., 2-17-12, Shibaura, Minato-Ku, Tokyo, 108-0023, Japan

Tel: 81-3-5419-2668 Fax: 81-3-5419-0018 jpservices@apacer.com

China

Apacer Electronic (Shanghai) Co., Ltd

Room D, 22/FL, No.2, Lane 600, JieyunPlaza, Tianshan RD, Shanghai, 200051, China

Tel: 86-21-6228-9939 Fax: 86-21-6228-9936 sales@apacer.com.cn

U.S.A.

Apacer Memory America, Inc.

46732 Lakeview Blvd., Fremont, CA 94538

Tel: 1-408-518-8699 Fax: 1-510-249-9551 sa@apacerus.com

Europe

Apacer Technology B.V.

Science Park Eindhoven 5051 5692 EB Son, The Netherlands

Tel: 31-40-267-0000 Fax: 31-40-290-0686 sales@apacer.nl

India

Apacer Technologies Pvt Ltd,

1874, South End C Cross, 9th Block Jayanagar, Bangalore-560069, India

Tel: 91-80-4152-9061/62 Fax: 91-80-4170-0215 sales india@apacer.com